L Number	Hits	Search Text	DB	Time stamp
-	603	(345/82-83).CCLS.	USPAT;	2003/11/18 12:18
			EPO; JPO;	
			IBM TDB	
- !	824	(345/76-81).CCLS.	USPĀT;	2002/07/15 14:28
			EPO; JPO;	
			IBM TDB	
ı -	11911	(current or voltage) near5 color	USPAT;	2002/07/15 14:40
		(0.000000000000000000000000000000000000	EPO; JPO;	
			IBM_TDB	
ı .	73	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and ((current or voltage)	USPAT;	2002/07/15 14:39
	"	near5 color)	EPO; JPO;	2002/07/15 14.57
, <u>, , , , , , , , , , , , , , , , , , </u>		11043 00101)	IBM TDB	
	2	("3740570").PN.	USPAT;	2002/07/15 14:32
_	_	(5740570).1 IV.	EPO; JPO;	2002/07/13 14.32
1				
j	25994	(TFT or (thin adj film adj transistor))	IBM_TDB	2002/11/19 10:12
-	23994	(1F1 or (unit adj tilli adj transistor))	USPAT;	2003/11/18 10:12
			EPO; JPO;	
	112	(/TPT = (41: - 41:01 - 11:4 - 14 - 1)	IBM_TDB	0000/11/10 11 07
-	113	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2003/11/18 11:05
'		color)	EPO; JPO;	
		(((2.45/02.02)	IBM_TDB	1
-	1	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and (((TFT or (thin adj	USPAT;	2002/07/15 14:39
		film adj transistor))) same ((current or voltage) near5 color))	EPO; JPO;	
			IBM_TDB	
-	6107	((current or voltage near2 control)) near5 color	USPAT;	2002/07/15 14:46
			EPO; JPO;	
			IBM_TDB	
-	20	((TFT or (thin adj film adj transistor))) same (((current or voltage near2	USPAT;	2003/11/18 10:15
		control)) near5 color)	EPO; JPO;	
			IBM_TDB	
-	715	((current or voltage) near2 control) near5 color	USPAT;	2002/07/15 14:48
			EPO; JPO;	
			IBM_TDB	
-	4	((TFT or (thin adj film adj transistor))) same (((current or voltage) near2	USPAT;	2002/07/15 14:48
		control) near5 color)	EPO; JPO;	
			IBM TDB	
-	2	jp-10039791-\$.did.	EPO; JPO;	2002/07/17 10:45
			DERWENT	
-	1 .	1998-184157.NRAN.	DERWENT	2002/07/17 10:46
· -	896	(TFT or (thin adj film adj transistor)) near5 size	USPAT;	2002/07/17 13:33
			EPO; JPO;	
	·		IBM_TDB	
-	16	("W/L" or "W adj L") same ((TFT or (thin adj film adj transistor)) near5	USPAT;	2002/07/17 13:33
, l		size)	EPO; JPO;	
			IBM TDB	
	2	JP-09236790-\$.did.	EPO; JPO;	2002/07/17 13:29
		,	DERWENT	
- 1	12497	("W/L" or ("W" adj "L"))	USPAT;	2002/07/17 13:34
			EPO; JPO;	
			IBM TDB	:
-	16	("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 13:34
		near5 size)	EPO; JPO;	2002/07/17 13.54
			IBM TDB	
_	0	(("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 13:34
İ		near5 size) not (("W/L" or "W adj L") same ((TFT or (thin adj film adj	EPO; JPO;	2002/07/17 15:54
		transistor)) near5 size))		
_	2	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L"))))	IBM_TDB	2002/07/17 12:25
1		((TFT or (thin ad) thim adj transistor)) same (("W/L" or ("W" adj "L")))) same color	USPAT;	2002/07/17 13:35
Ì		Same color	EPO; JPO;	
_	1	("4810060") DN	IBM_TDB	0000/07/17 11 2
-	¹	("4810060").PN.	USPAT;	2002/07/17 14:25
			EPO; JPO;	
_		("A60027A" "A6015A6" "A716A02" "A720170" "A700170"	IBM_TDB	
-	6	("4600274" "4601546" "4716403" "4728172" "4728175"	USPAT	2002/07/17 14:25
		"4761058").PN.	L	<u> </u>

			* *****	1 0000/05/15
-	15	4810060.URPN.	USPAT	2002/07/17 14:26
-	2	(TFT or (thin adj film adj transistor)) same (emission adj efficiency)	USPAT;	2002/07/18 09:24
			EPO; JPO;	
			IBM TDB	
_	537	(TFT or (thin adj film adj transistor)) same (electroluminescence or "EL")	USPĀT;	2004/05/25 10:17
-		(11 1 or (min adj min adj manbioli)) same (electronimicoconico el 222)	EPO; JPO;	
			IBM_TDB	
	120	(TET on (thin adi film adi tuancistan)) sama (alastraluminassanas)	_	2002/07/17 15:27
-	129	(TFT or (thin adj film adj transistor)) same (electroluminescence)	USPAT;	2002/07/17 15:27
			EPO; JPO;	
			IBM_TDB	
-	20	(TFT or (thin adj film adj transistor)) same (electroluminescence adj	USPAT;	2002/07/17 15:35
		element)	EPO; JPO;	İ
			IBM_TDB	
-	3250	switching near3 (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:37
			EPO; JPO;	1
			IBM_TDB	1
-	2161	driving near3 (TFT or (thin adj film adj transistor))	USPĀT;	2002/07/17 15:38
		The straining means (11 1 or (min and min and	EPO; JPO;	
			IBM TDB	
	230	(switching near3 (TFT or (thin adj film adj transistor))) same (driving	_	2002/07/17 15:27
-	230		USPAT;	2002/07/17 15:37
1		near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	
			IBM_TDB	l
-	171	(switching near3 (TFT or (thin adj film adj transistor))) with (driving	USPAT;	2002/07/17 15:37
		near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	
			IBM_TDB	
-	401	switching adj (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
			EPO; JPO;	
			IBM_TDB	
l <u>-</u>	478	driving adj (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
	''	diving adj (11 1 or (min adj min adj maisistor))	EPO; JPO;	2002/07/17 13.36
	1.7	(IBM_TDB	2002/05/15 15 20
-	17	(switching adj (TFT or (thin adj film adj transistor))) same (driving adj	USPAT;	2002/07/17 15:38
	1	(TFT or (thin adj film adj transistor)))	EPO; JPO;	
	1		IBM_TDB	
-	26028	(TFT or (thin adj film adj transistor))	USPAT;	2002/07/18 09:23
			EPO; JPO;	
			IBM_TDB	
-	62	((TFT or (thin adj film adj transistor))) and (emission adj efficiency)	USPAT;	2002/07/18 09:24
1			EPO; JPO;	1
			IBM_TDB	
-	214	((TFT or (thin adj film adj transistor))) and (chromaticity)	USPAT;	2002/07/18 09:25
	ĺ	(, , , , , , , , , , , , , , , , , , ,	EPO; JPO;	2002/0//10 0//20
			IBM_TDB	
	3	(((TFT or (thin adj film adj transistor))) and (emission adj efficiency))	USPAT;	2002/07/19 00:25
		and (((TFT or (thin adj film adj transistor))) and (chromaticity))		2002/07/18 09:25
		and (((11 1 or turns any main any mainsister))) and (chromaticity))	EPO; JPO;	
1_		("5550066" "5694365") DNI	IBM_TDB	2002/05/10 00 00
-	2	("5550066" "5684365").PN.	USPAT	2002/07/18 09:29
-	2	("6204610").PN.	USPAT;	2002/07/18 10:24
			DERWENT	
-	1	2000-651206.NRAN.	DERWENT	2002/07/18 10:25
-	1	("5684365").PN.	USPAT;	2002/07/18 10:57
			EPO; JPO;	
1			IBM_TDB	
1 -	1	("6072272").PN.	USPAT;	2002/07/18 12:02
1			EPO; JPO;	
			IBM TDB	
-	8	("4193015" "4220892" "5045750" "5311337" "5317437"	USPAT	2002/07/18 11:49
		"5467422" "5565754" "5654729").PN.	OBIAI	2002/07/10 11.49
1.	0	6072272.URPN.	LICDAT	2002/07/19 11 50
1.			USPAT	2002/07/18 11:50
1 -	2	("6366025").PN.	USPAT;	2002/07/18 12:02
1			EPO; JPO;	
1		2004 0000 (700 170 170 170 170 170 170 170 170 170	DERWENT	
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:02
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:04
	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:05

-	1	("6072272").PN.	USPAT;	2002/07/18 15:04
			EPO; JPO;	
	1	(#C12172C#\ DNI	IBM_TDB	2002/07/19 15:04
-	1	("6121726").PN.	USPAT; EPO; JPO;	2002/07/18 15:04
İ			IBM_TDB	
1.	0	jp-1173928-\$.did.	USPAT;	2003/04/07 13:06
ŀ	ľ)	US-PGPUB;	2003/04/07 13:00
			EPO; JPO;	
			IBM_TDB	
-	0	jp-1173928-\$.did.	EPO; JPO;	2003/04/07 13:06
			DERWENT	
-	2	jp-01173928-\$.did.	EPO; JPO;	2003/04/07 13:12
		:- 001172029 6 4:4	DERWENT	0002/04/05 12 05
ļ -	0	jp-001173928-\$.did.	EPO; JPO; DERWENT	2003/04/07 13:07
1.	1	("6204610").PN.	USPAT;	2003/04/07 13:12
_	•	(0204010).114.	US-PGPUB;	2003/04/07 13.12
ĺ			EPO; JPO;	
İ			IBM_TDB	
-	2	("6204610").PN.	USPĀT;	2003/04/07 13:12
			DERWENT	
-	1	2000-651206.NRAN.	DERWENT	2003/04/07 13:13
-	1	("5134253").PN.	USPAT;	2003/04/08 15:16
			EPO; JPO;	
_	1	("4587378").PN.	IBM_TDB USPAT;	2002/04/09 15:16
-	1	(4507576).114.	EPO; JPO;	2003/04/08 15:16
			IBM_TDB	
-	1	("4645869").PN.	USPAT;	2003/04/08 15:17
			EPO; JPO;	
			IBM_TDB	
-	1	("4818827").PN.	USPAT;	2003/04/08 15:17
			EPO; JPO;	
1	,	(#4007511#) 751	IBM_TDB	
-	1	("4897511").PN.	USPAT;	2003/04/08 15:17
			EPO; JPO; IBM_TDB	
-	1	("5159159").PN.	USPAT;	2003/04/08 15:18
			EPO; JPO;	2003/01/00 13:10
			IBM_TDB	
-	1	("5530209").PN.	USPAT;	2003/04/08 15:18
			EPO; JPO;	
_	ı	("5563381").PN.	IBM_TDB	2002/04/00 15 10
		(3303381).FN.	USPAT; EPO; JPO;	2003/04/08 15:18
			IBM_TDB	
-	1	("5977491").PN.	USPAT;	2003/04/08 15:19
			EPO; JPO;	
			IBM_TDB	
-	1	("6239790").PN.	USPAT;	2003/04/08 15:19
			EPO; JPO;	
 	1	("6259491").PN.	IBM_TDB	2002/04/09 15:20
	· [(023)471).111.	USPAT; EPO; JPO;	2003/04/08 15:20
			IBM_TDB	
-	1	("6304251").PN.	USPAT;	2003/04/08 15:20
			EPO; JPO;	
		(14.60.00.00)	IBM_TDB	
-	1	("4625075").PN.	USPAT;	2003/04/08 15:20
			EPO; JPO;	
_	1	("4001677").PN.	IBM_TDB	2002/04/09 15:44
	'	(10010// Jilli	USPAT; EPO; JPO;	2003/04/08 15:44
			IBM_TDB	

			·	
-	7	("5742129" "5745085" "5828181" "5886474" "5990629" "6028573" "6084579").PN.	USPAT	2003/04/17 11:25
-	4	TFT-EL same TFT-LCD	USPAT;	2003/11/18 10:10
			US-PGPUB;	
]		EPO; JPO;	
	İ		IBM_TDB	
-	29624	(TFT or (thin adj film adj transistor))	USPAT;	2003/11/18 10:29
			EPO; JPO;	
			IBM_TDB	
-	652	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	USPAT;	2003/11/18 11:07
			EPO; JPO;	
	10231	((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj crystal	IBM_TDB USPAT;	2003/11/18 10:30
	10231	adj (diode or display)))	EPO; JPO;	2003/11/16 10.30
j		duj (diode or display)))	IBM TDB	
ļ <u>-</u>	143	((((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	USPAT;	2003/11/18 10:14
		same (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj	US-PGPUB;	2003/11/10 10:11
		crystal adj (diode or display))))	EPO; JPO;	
		• • • • • • • • • • • • • • • • • • • •	IBM TDB	
-	80	((((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	USPĀT;	2003/11/18 11:06
		same (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj	EPO; JPO;	
		crystal adj (diode or display))))) and @ad<19991004	IBM_TDB	
[-	22346	(TFT or (thin adj film adj transistor))	USOCR	2003/11/18 10:32
-	1	(((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	USOCR	2003/11/18 10:31
		and (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj		
	4	crystal adj (diode or display)))) ((TET or (thin adj film adj tennajatar))) with (LCD or (liquid adj arrest)	LICOCD	2002/11/19 10:21
-	4	((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj crystal adj (diode or display)))	USOCR	2003/11/18 10:31
_	1743	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	USOCR	2003/11/18 10:33
_	144	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2003/11/18 10:33
		color)	EPO; JPO;	2003/11/10 11:03
		,	IBM TDB	
-	105	(((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPĀT;	2003/11/18 11:07
		color)) and @ad<19991004	EPO; JPO;	
			IBM_TDB	
-	652	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	USPAT;	2003/11/18 11:08
			EPO; JPO;	
			IBM_TDB	
-	6	(((TFT or (thin adj film adj transistor))) same ((current or voltage) near5 color)) and (((TFT or (thin adj film adj transistor))) with (EL or	USPAT;	2003/11/18 11:08
		color) / and (((1 f 1 or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	EPO; JPO; IBM_TDB	
-	0	((((TFT or (thin adj film adj transistor)))) same ((current or voltage) near5	USPAT;	2003/11/18 11:08
		color)) and (((TFT or (thin adj film adj transistor))) with (EL or	EPO; JPO;	2003/11/10 11.00
		electrolumisc\$5))) and @ad<19991004	IBM TDB	
-	54456	(EL or electrolumisc\$5)	USPAT;	2003/11/18 11:08
			EPO; JPO;	_ i
			IBM_TDB	
-	12	(((TFT or (thin adj film adj transistor)))) same ((current or voltage) near5	USPAT;	2003/11/18 11:08
		color)) and ((EL or electrolumisc\$5))	EPO; JPO;	
	ا ۾	((((TET on (thin od: 61m od: toomsints \)) (()	IBM_TDB	2004/05/25 10 15
•	4	((((TFT or (thin adj film adj transistor))) same ((current or voltage) near5 color)) and ((EL or electrolumisc\$5))) and @ad<19991004	USPAT;	2004/05/25 10:43
		Color,) and ((EL of electrofulliseps))) and (wad~19991004	EPO; JPO; IBM TDB	
_	1	("4810060").PN.	USPAT;	2003/11/18 11:11
		()	US-PGPUB;	2003/11/10 11.11
			EPO; JPO;	
			IBM_TDB	
-	6	("4600274" "4601546" "4716403" "4728172" "4728175"	USPAT	2003/11/18 11:11
		"4761058").PN.		
-	15	4810060.URPN.	USPAT	2003/11/18 11:11
-	1	("6252248").PN.	USPAT;	2003/11/18 12:19
			EPO; JPO;	
	15	4810060.URPN.	IBM_TDB	2004/05/25 12 12
	1.0	TOTOVOO.OIG IV.	USPAT	2004/05/25 10:12

		-		
-	153	(TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L")))	USPAT; EPO; JPO;	2004/05/25 10:21
_	71213	electroluminescen\$3 or "EL" or electro\$11uminescen\$3	IBM_TDB USPAT;	2004/05/25 11:33
	, , , ,		EPO; JPO; IBM_TDB	
-	18	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L"))))	USPĀT;	2004/05/25 10:25
		and (electroluminescen\$3 or "EL" or electro\$1luminescen\$3)	EPO; JPO; IBM_TDB	
-	153	(TFT or (thin adj film adj transistor)) same (("W\$1L" or ("W" adj "L")))	USPĀT; EPO; JPO;	2004/05/25 10:21
			IBM_TDB	
-	153	(TFT or ((thin adj film) or thin\$1film) adj transistor) same (("W\$1L" or ("W" adj "L")))	USPAT; EPO; JPO;	2004/05/25 10:42
	10	, , , , , , , , , , , , , , , , , , , ,	IBM_TDB	2004/05/25 10:42
-	18	((TFT or ((thin adj film) or thin\$1film) adj transistor) same (("W\$1L" or ("W" adj "L")))) and (electroluminescen\$3 or "EL" or	USPAT; EPO; JPO;	2004/05/25 10:42
_	2217	electro\$1luminescen\$3) (TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)	IBM_TDB USPAT;	2004/05/25 11:33
	2217	(11 Tot ((ann adj film) of dimprimity adj dialisistor) with (size)	EPO; JPO;	2004/05/25 11:55
_	339	((TFT or ((thin adj film) or thin\$1 film) adj transistor) with (size)) and	IBM_TDB USPAT;	2004/05/25 10:43
		(electroluminescen\$3 or "EL" or electro\$1luminescen\$3)	EPO; JPO;	
-	58	((TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)) same	IBM_TDB USPAT;	2004/05/25 10:43
		(electroluminescen\$3 or "EL" or electro\$1luminescen\$3)	EPO; JPO;	
-	29	(((TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)) same	IBM_TDB USPAT;	2004/05/25 11:35
		(electroluminescen\$3 or "EL" or electro\$1luminescen\$3)) and @ad<19991004	EPO; JPO; IBM_TDB	
-	71213	electroluminescen\$3 or "EL" or electro\$1luminescen\$3	USPAT;	2004/05/25 11:33
			EPO; JPO; IBM_TDB	
-	31627	TFT or (((thin adj film) or thin\$1film) adj transistor)	USPAT;	2004/05/25 11:34
			EPO; JPO; IBM_TDB	
-	246442	width with length	USPAT;	2004/05/25 11:35
			EPO; JPO; IBM_TDB	
-	708	(TFT or (((thin adj film) or thin\$1film) adj transistor)) with (width with length)	USPAT; EPO; JPO;	2004/05/25 11:35
			IBM_TDB	
-	12	(electroluminescen\$3 or "EL" or electro\$11uminescen\$3) same ((TFT or (((thin adj film) or thin\$1film) adj transistor)) with (width with length))	USPAT; EPO; JPO;	2004/05/25 11:36
			IBM_TDB	
-	3	((electroluminescen\$3 or "EL" or electro\$1luminescen\$3) same ((TFT or (((thin adj film) or thin\$1film) adj transistor)) with (width with length)))	USPAT; EPO; JPO;	2004/05/25 11:36
	150	and @ad<19991004	IBM_TDB	2004/06/25 11 5
-	150	(electroluminescen\$3 or "EL" or electro\$11uminescen\$3) and ((TFT or (((thin adj film) or thin\$1film) adj transistor)) with (width with length))	USPAT; EPO; JPO;	2004/05/25 11:36
_	57	((electroluminescen\$3 or "EL" or electro\$1luminescen\$3) and ((TFT or	IBM_TDB	2004/05/25 11:27
	"	(((thin adj film) or thin\$1film) adj transistor)) with (width with length)))	USPAT; EPO; JPO;	2004/05/25 11:37
_	1	and @ad<19991004 ("5684365").PN.	IBM_TDB USPAT;	2004/05/25 12:57
		,	US-PGPUB;	200 1103/23 12.37
			EPO; JPO; IBM_TDB	
-	10	("3807037" "3913090" "4006383" "4885432" "5073446" "5151629" "5276380" "5294870" "5399936" "5483082").PN.	USPAT	2004/05/25 12:57
	81	5684365.URPN.	USPAT	2004/05/25 12:57